

Features

- APD with 7 mm² active area
- 3000 µm diameter active area
- High gain at low bias voltage
- Fast rise time, low capacitance
- Optimum gain: 50-60

Description

Circular active area APD chip with 3000 µm diameter. Metal can type hermetic TO5 package with clear glass window.

Application

- Laser range finder
- High speed photometry
- High speed optical communications
- Medical equipment

RoHS

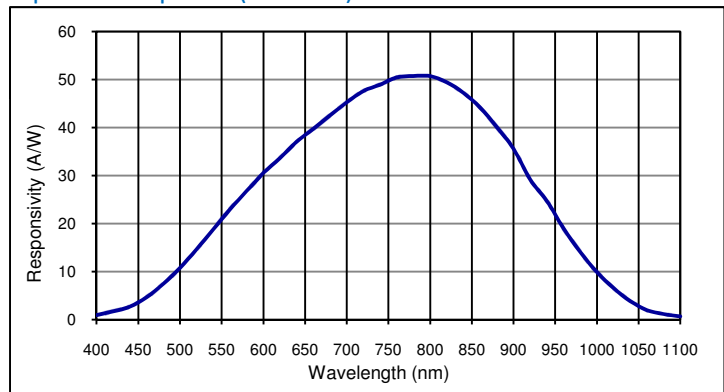
2002/95/EC



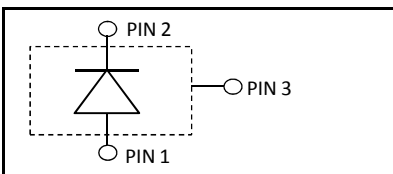
Absolute maximum ratings

Symbol	Parameter	Min	Max	Unit
T _{STG}	Storage temp	-55	125	°C
T _{OP}	Operating temp	-40	100	°C
M _{max}	Gain (I _{PO} = 1 nA)	200		
I _{PEAK}	Peak DC current		0.25	mA

Spectral response (M = 100)



Schematic



Electro-optical characteristics @ 22°C

Symbol	Characteristic	Test Condition	Min	Typ	Max	Unit
	Active area		diameter 3000			µm
	Active area		7.07			mm ²
I _D	Dark current	M = 100		30		nA
C	Capacitance	M = 100		45		pF
	Responsivity	M = 100; λ = 800 nm	45	50		A/W
t _R	Rise time	M = 100; λ = 905 nm; R _L = 50 Ω		2		ns
	Cut-off frequency	-3dB		0.18		GHz
V _{BR}	Breakdown voltage	I _R = 2 µA, V _{BR} - binning available	80		200	V
	Temperature coefficient	Change of V _{BR} with temperature		0.45		V/K
	Excess noise factor	M = 100		2.2		
	Excess noise index	M = 100		0.2		
	N.E.P.	M = 100; λ = 800 nm		4.5 E-13		W/√Hz
	Noise current	M = 100; λ = 800 nm		22.8		pA/√Hz

European, International Sales:



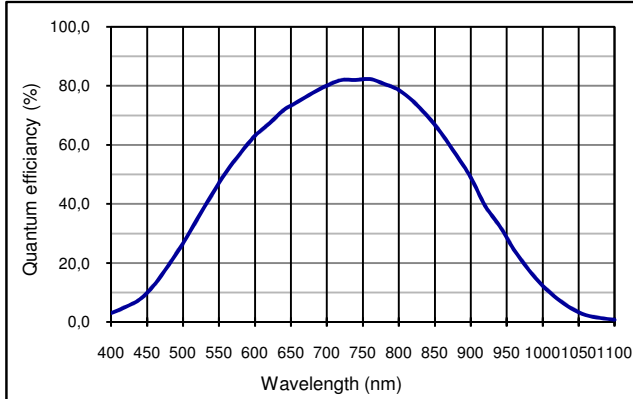
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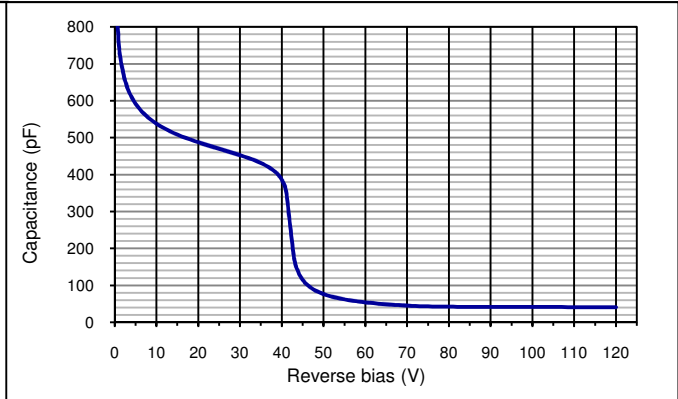


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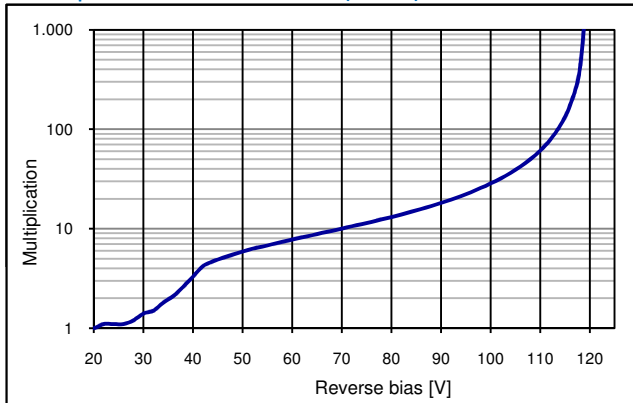
Quantum efficiency (22 °C)



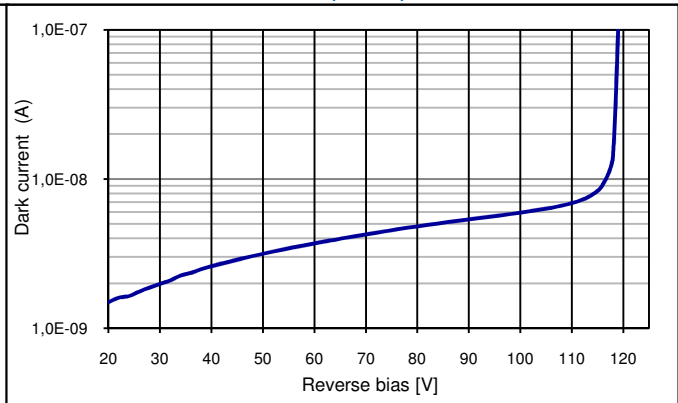
Capacitance as fct of reverse bias (22 °C)



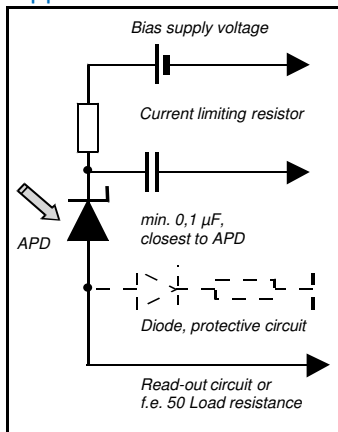
Multiplication as fct of bias (22 °C)



Dark current as fct of bias (22 °C)



Application hints:



- Current should be limited by a protecting resistor or current limiting - IC inside the power supply
- For low light level applications blocking of ambient light should be used
- For high gain applications bias voltage should be temperature compensated
- Please consider basic ESD protection while handling
- Use low noise read-out - IC
- For further questions please refer to document "Instructions for handling and processing"
- Optimum gain: 50-60

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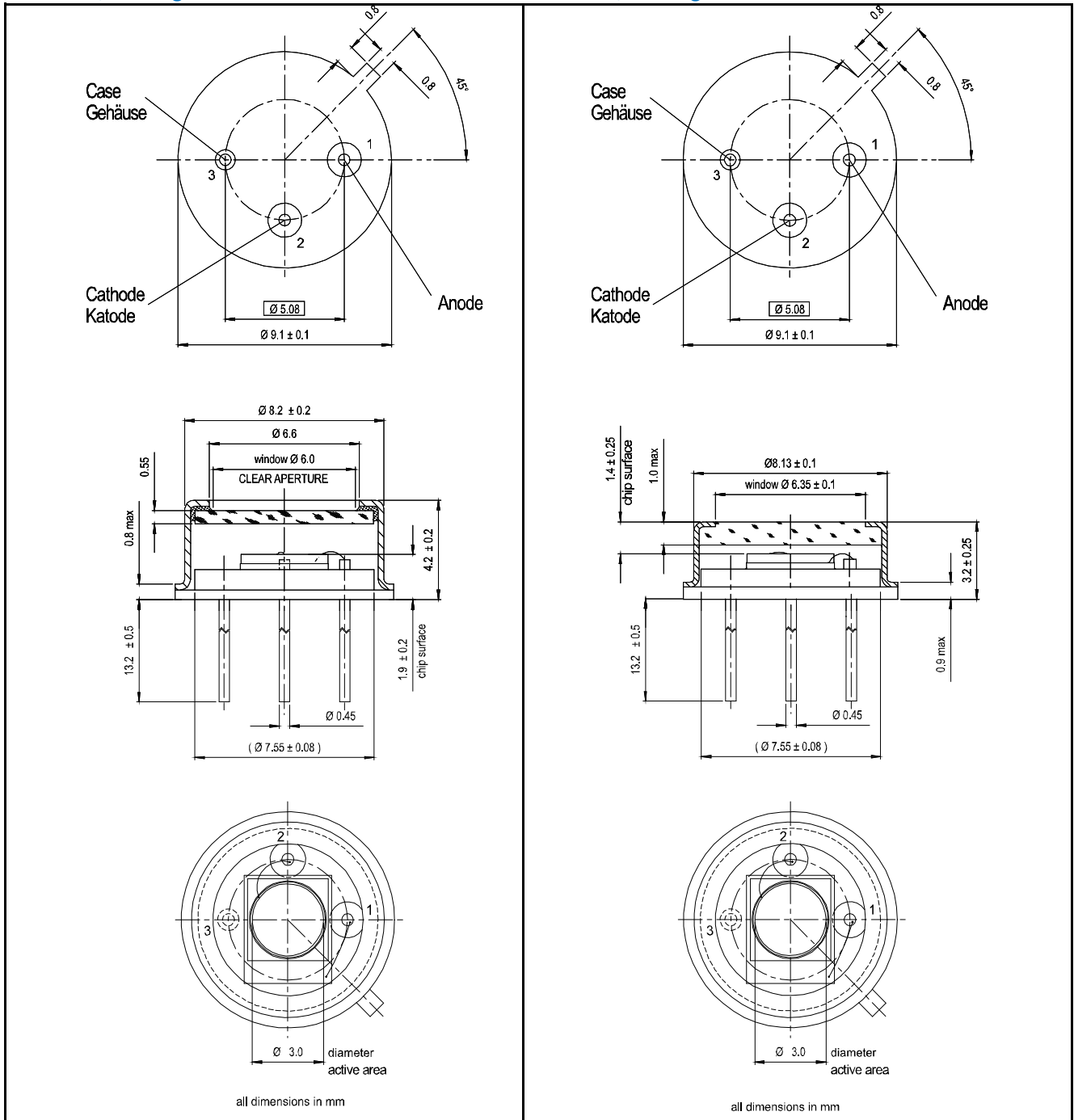
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501194; Package: TO5i

500158; Package: TO5i



Package dimension:

Small quantities: Foam pad, boxed (12 cm x 16.5 cm)

Disclaimer: Due to our strive for continuous improvement, specifications are subject to change within our PCN policy according to JESD46C.

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